

TOSHIBA Field Effect Transistor Silicon P, N Channel MOS Type (U-MOS IV / U-MOS III)

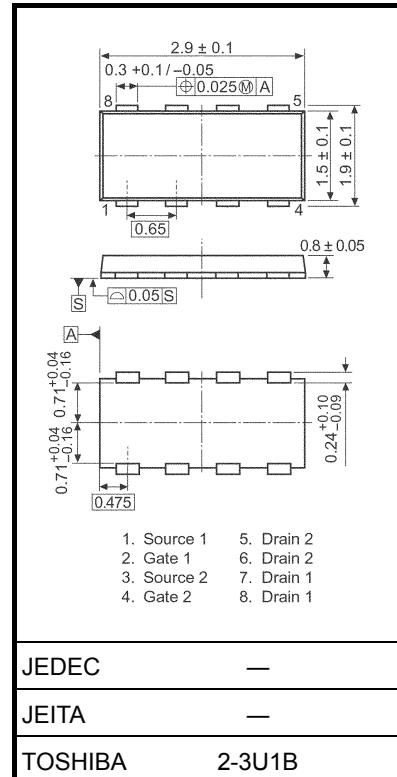
TPCF8402

Portable Equipment Applications

Motor Drive Applications

DC-DC Converter Applications

Unit: mm



Weight: 0.011 g (typ.)

Absolute Maximum Ratings (Ta = 25°C)

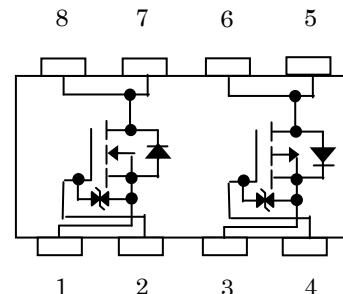
Characteristics		Symbol	Rating		Unit
Drain-source voltage		V _{DSS}	-30	30	V
Drain-gate voltage (R _{GS} = 20 kΩ)		V _{DGR}	-30	30	V
Gate-source voltage		V _{GSS}	±20	±20	V
Drain current	DC (Note 1)	I _D	-3.2	4.0	A
	Pulse (Note 1)	I _{DP}	-12.8	16.0	
Drain power dissipation (t = 5 s) (Note 2a)	Single-device operation (Note 3a)	P _D (1)	1.35	1.35	W
	Single-device value at dual operation (Note 3b)	P _D (2)	1.12	1.12	
Drain power dissipation (t = 5 s) (Note 2b)	Single-device operation (Note 3a)	P _D (1)	0.53	0.53	
	Single-device value at dual operation (Note 3b)	P _D (2)	0.33	0.33	
Single pulse avalanche energy (Note 4)	E _{AS}	0.67	2.6	mJ	
Avalanche current	I _{AR}	-1.6	2.0	A	
Repetitive avalanche energy Single-device value at dual operation (Note 2a, 3b, 5)	E _{AR}	0.11		mJ	
Channel temperature	T _{ch}	150		°C	
Storage temperature range	T _{stg}	-55 to 150		°C	

Note: For Notes 1 to 5, refer to the next page.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic-sensitive device. Handle with caution.

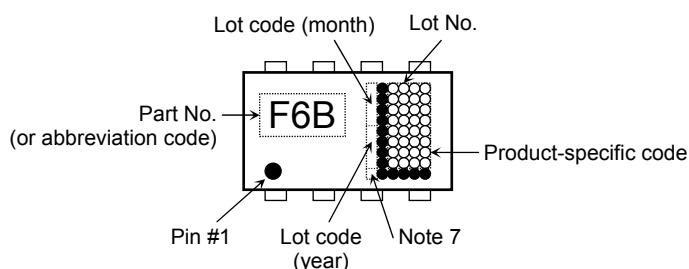
Circuit Configuration



Thermal Characteristics

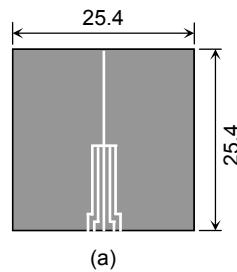
Characteristics	Symbol	Max	Unit
Thermal resistance, channel to ambient ($t = 5$ s) (Note 2a)	Single-device operation (Note 3a) R_{th} (ch-a) (1)	92.6	°C/W
	Single-device value at dual operation (Note 3b) R_{th} (ch-a) (2)	111.6	
Thermal resistance, channel to ambient ($t = 5$ s) (Note 2b)	Single-device operation (Note 3a) R_{th} (ch-a) (1)	235.8	°C/W
	Single-device value at dual operation (Note 3b) R_{th} (ch-a) (2)	378.8	

Marking (Note 6)

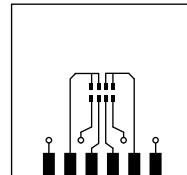


Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: (a) Device mounted on a glass-epoxy board (a) (b) Device mounted on a glass-epoxy board (b)



FR-4
25.4 × 25.4 × 0.8
(Unit: mm)



FR-4
25.4 × 25.4 × 0.8
(Unit: mm)

Note 3: a) The power dissipation and thermal resistance values are shown for a single device.

(During single-device operation, power is only applied to one device.)

b) The power dissipation and thermal resistance values are shown for a single device.

(During dual operation, power is evenly applied to both devices.)

Note 4: P Channel: $V_{DD} = -24$ V, $T_{ch} = 25^\circ\text{C}$ (initial), $L = 0.2$ mH, $R_G = 25 \Omega$, $I_{AR} = -1.6$ A

N Channel: $V_{DD} = 24$ V, $T_{ch} = 25^\circ\text{C}$ (initial), $L = 0.5$ mH, $R_G = 25 \Omega$, $I_{AR} = 2.0$ A

Note 5: Repetitive rating: Pulse width limited by maximum channel temperature.

Note 6: “●” on the lower left of the marking indicates Pin 1.

Note 7 A dot marking identifies the indication of product Labels.

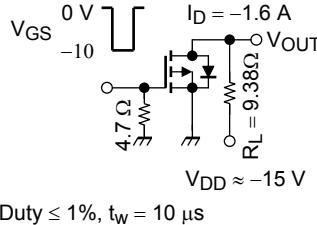
Without a dot: [[Pb]]/INCLUDES > MCV

With a dot: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

P-channel

Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current	I _{GSS}	V _{GS} = ±16 V, V _{DS} = 0 V	—	—	±10	µA
Drain cut-off current	I _{DSS}	V _{DS} = -30 V, V _{GS} = 0 V	—	—	-10	µA
Drain-source breakdown voltage	V _{(BR) DSS}	I _D = -10 mA, V _{GS} = 0 V	-30	—	—	V
	V _{(BR) DSX}	I _D = -10 mA, V _{GS} = 20 V	-15	—	—	
Gate threshold voltage	V _{th}	V _{DS} = -10 V, I _D = -1 mA	-0.8	—	-2.0	V
Drain-source ON resistance	R _{DS (ON)}	V _{GS} = -4.5 V, I _D = -1.6 A	—	80	105	mΩ
		V _{GS} = -10 V, I _D = -1.6 A	—	60	72	
Forward transfer admittance	Y _{fs}	V _{DS} = -10 V, I _D = -1.6 A	2.9	5.9	—	S
Input capacitance	C _{iss}	V _{DS} = -10 V, V _{GS} = 0 V, f = 1 MHz	—	600	—	pF
Reverse transfer capacitance	C _{rss}		—	60	—	
Output capacitance	C _{oss}		—	70	—	
Switching time	Rise time	t _r		—	5.3	—
	Turn-on time	t _{on}		—	12	—
	Fall time	t _f		—	8.4	—
	Turn-off time	t _{off}		—	34	—
Total gate charge (gate-source plus gate-drain)	Q _g	V _{DD} ≈ -24 V, V _{GS} = -10 V, I _D = -3.2 A	—	14	—	nC
Gate-source charge 1	Q _{gs1}		—	1.4	—	
Gate-drain ("miller") charge	Q _{gd}		—	2.7	—	

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Drain reverse current	I _{DRP}	—	—	—	-12.8	A
Forward voltage (diode)	V _{DSF}	I _{DR} = -3.2 A, V _{GS} = 0 V	—	—	1.2	V

N-channel

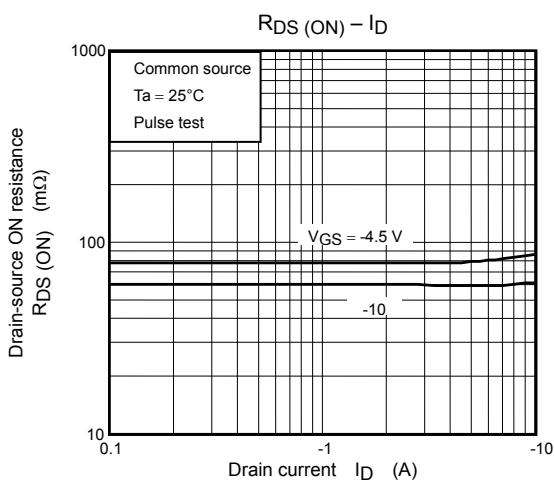
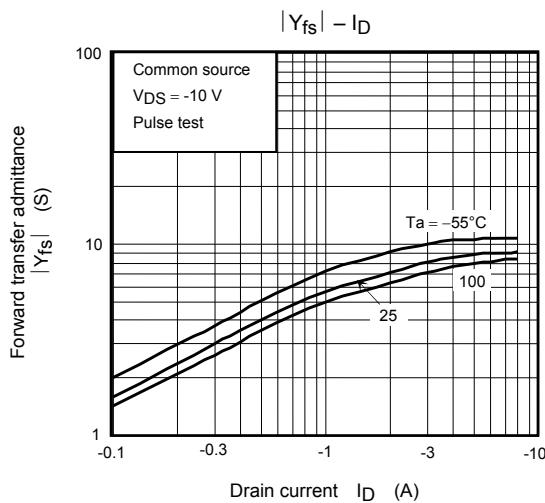
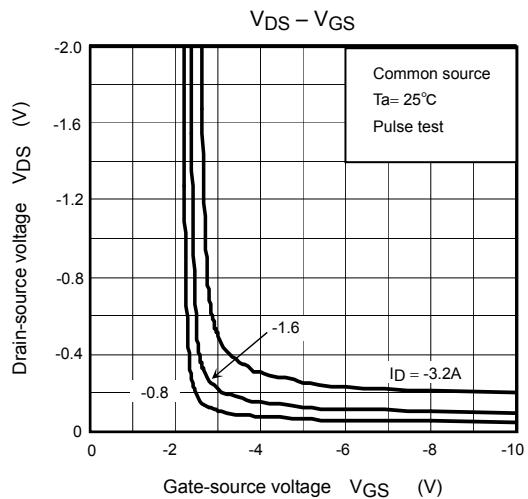
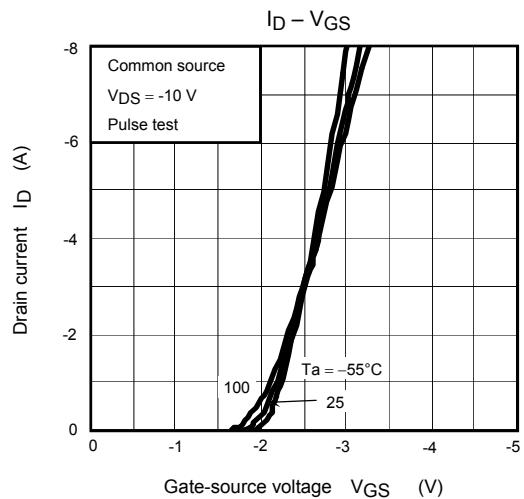
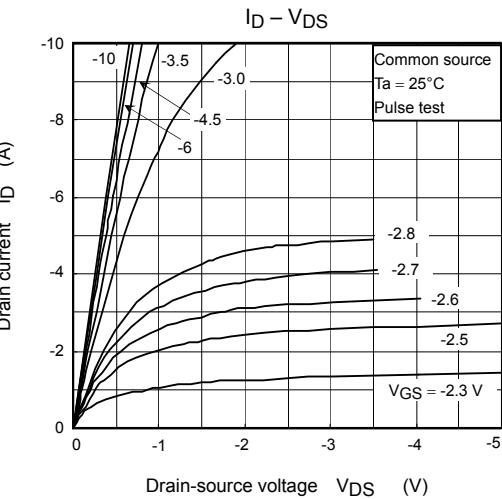
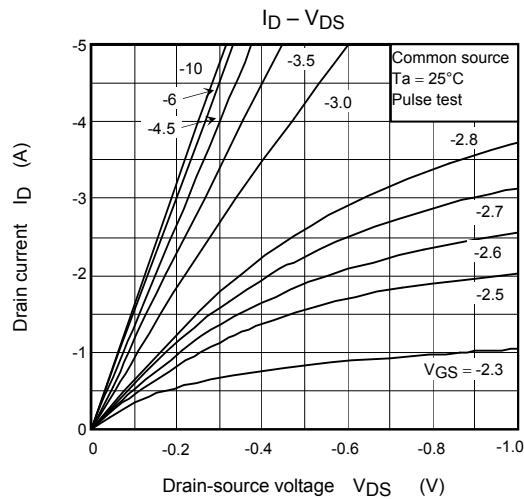
Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit	
Gate leakage current	I _{GSS}	V _{GS} = ±16 V, V _{DS} = 0 V	—	—	±10	µA	
Drain cut-off current	I _{DSS}	V _{DS} = 30 V, V _{GS} = 0 V	—	—	10	µA	
Drain-source breakdown voltage	V _{(BR) DSS}	I _D = 10 mA, V _{GS} = 0 V	30	—	—	V	
	V _{(BR) DSX}	I _D = 10 mA, V _{GS} = -20 V	15	—	—		
Gate threshold voltage	V _{th}	V _{DS} = 10 V, I _D = 1 mA	1.3	—	2.5	V	
Drain-source ON resistance	R _{D(S) (ON)}	V _{GS} = 4.5 V, I _D = 2.0 A	—	58	77	mΩ	
		V _{GS} = 10 V, I _D = 2.0 A	—	38	50		
Forward transfer admittance	Y _{fsl}	V _{DS} = 10 V, I _D = 2.0 A	3.4	6.8	—	S	
Input capacitance	C _{iss}	V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz	—	470	—	pF	
Reverse transfer capacitance	C _{rss}		—	60	—		
Output capacitance	C _{oss}		—	80	—		
Switching time	Rise time	t _r	 V _{GS} 10 V 0 V ID = 2.0 A V _{OUT} RL = 7.5 Ω V _{DD} ≈ 15 V Duty ≤ 1%, t _w = 10 µs	—	5.2	—	ns
	Turn-on time	t _{on}		—	8.3	—	
	Fall time	t _f		—	4.0	—	
	Turn-off time	t _{off}		—	22	—	
Total gate charge (gate-source plus gate-drain)	Q _g	V _{DD} ≈ 24 V, V _{GS} = 10 V, I _D = 4 A	—	10	—	nC	
Gate-source charge 1	Q _{gs1}		—	1.7	—		
Gate-drain ("miller") charge	Q _{gd}		—	2.4	—		

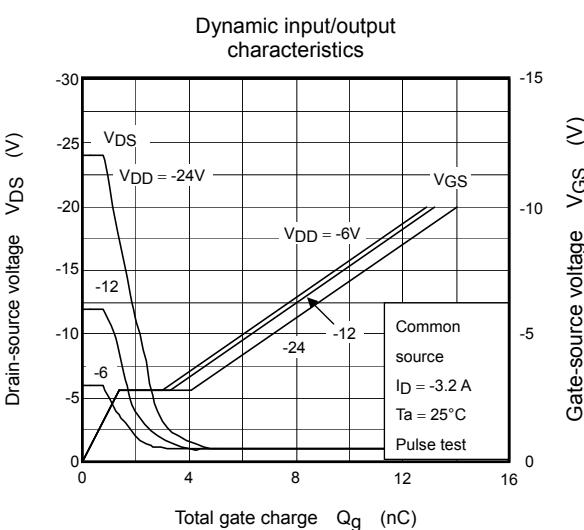
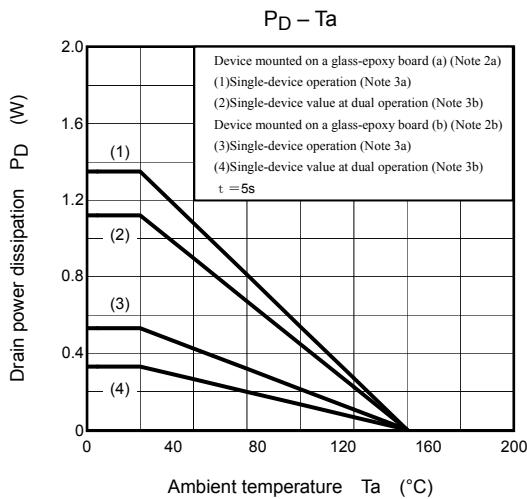
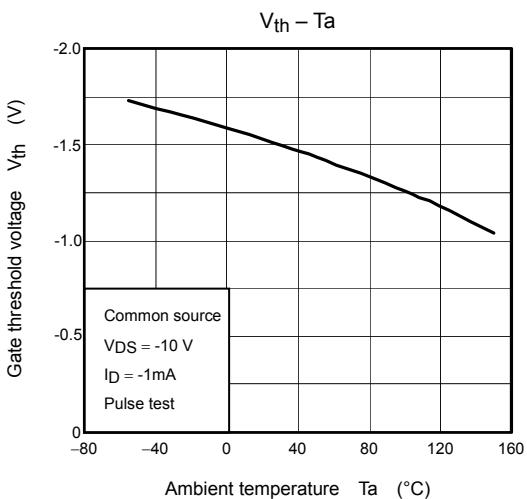
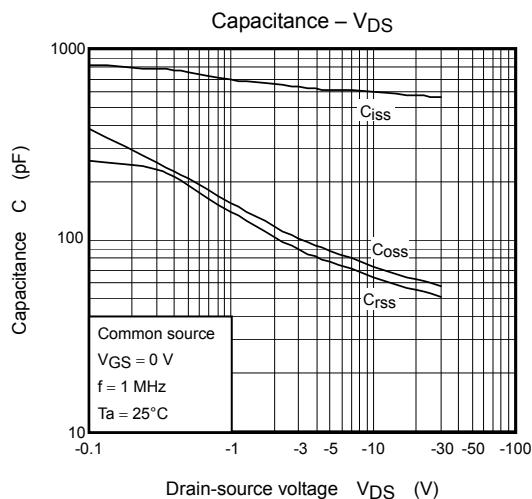
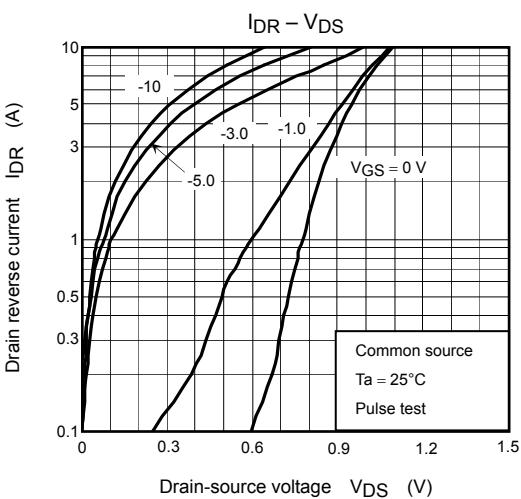
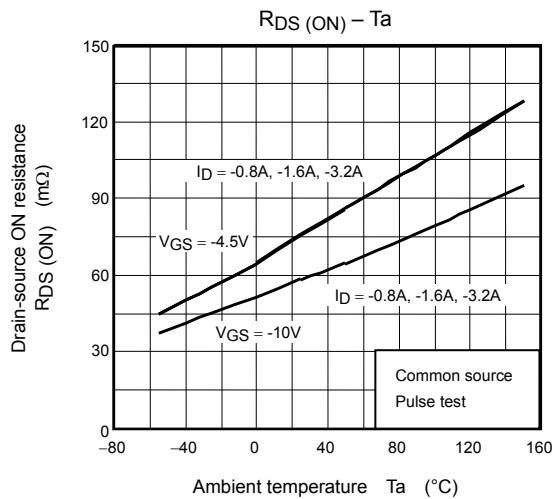
Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Drain reverse current Pulse (Note 1)	I _{DRP}	—	—	—	16.0	A
Forward voltage (diode)	V _{DSF}	I _{DR} = 4.0 A, V _{GS} = 0 V	—	—	-1.2	V

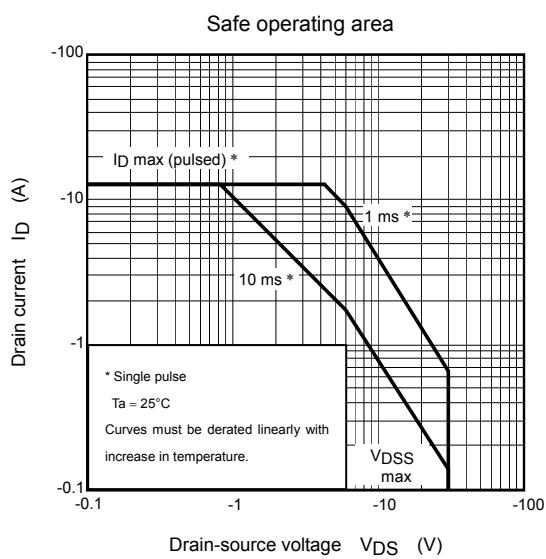
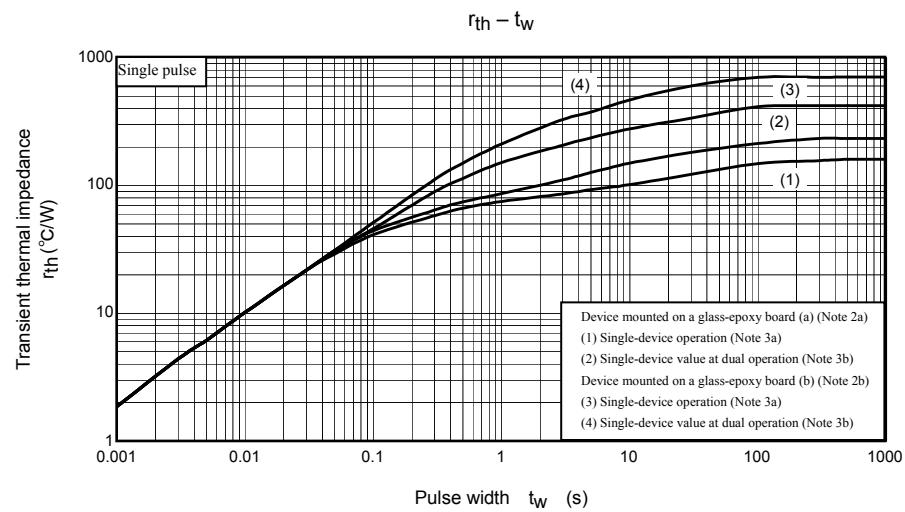
P-channel



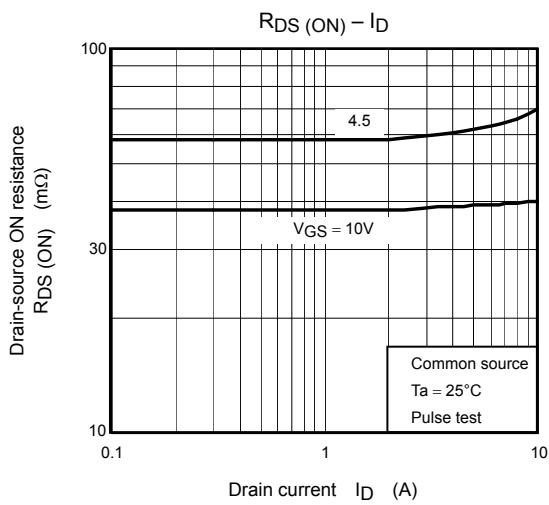
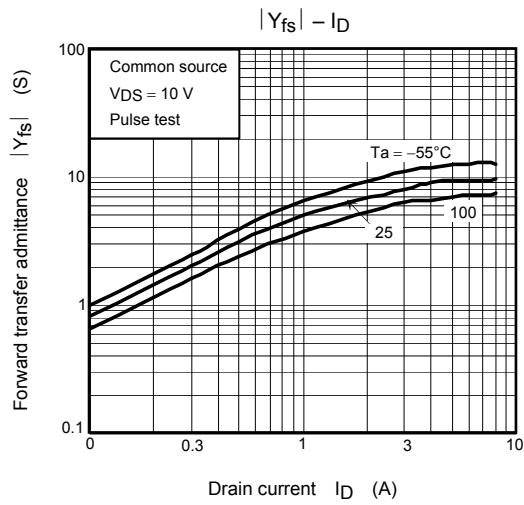
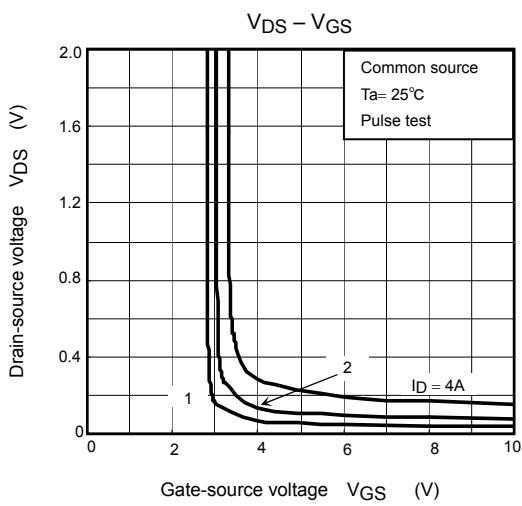
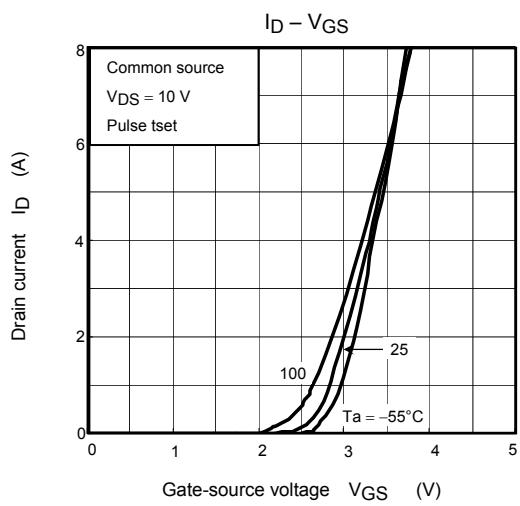
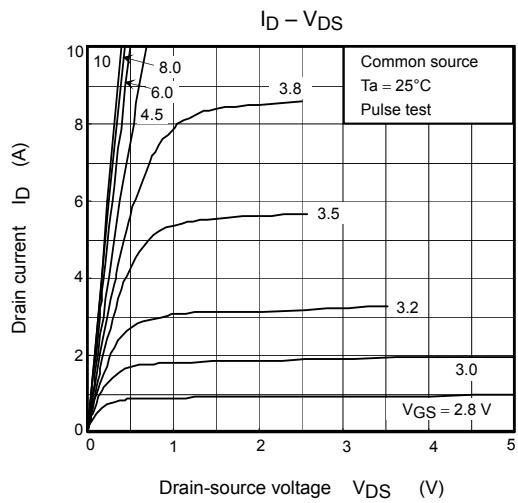
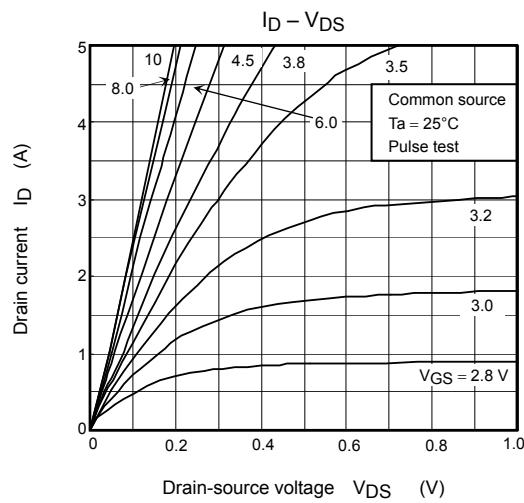
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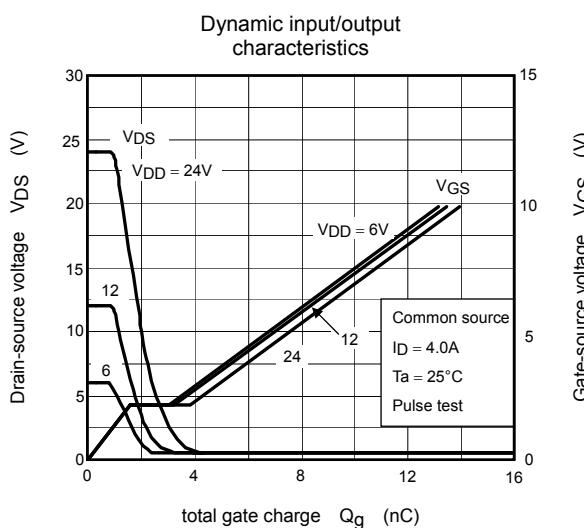
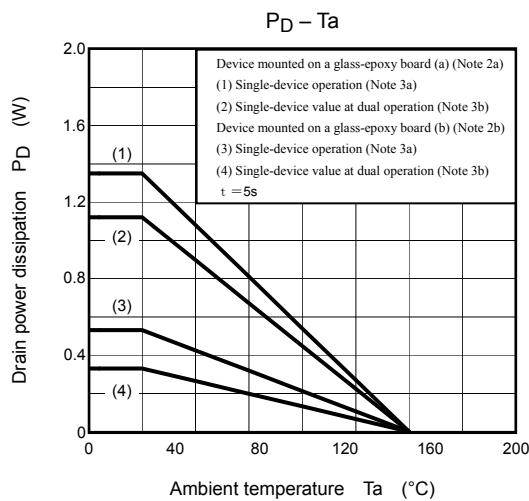
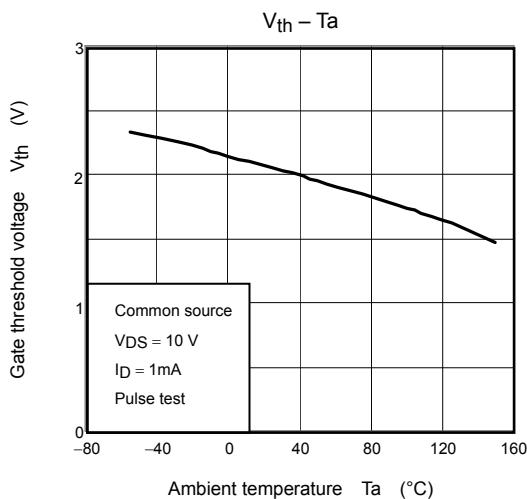
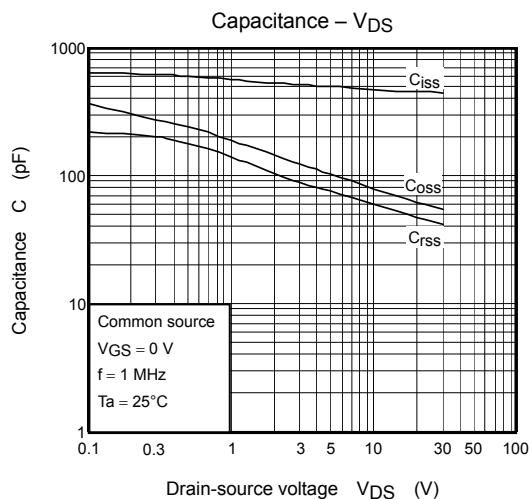
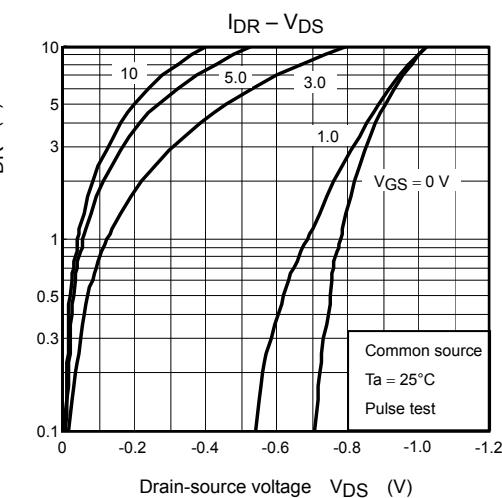
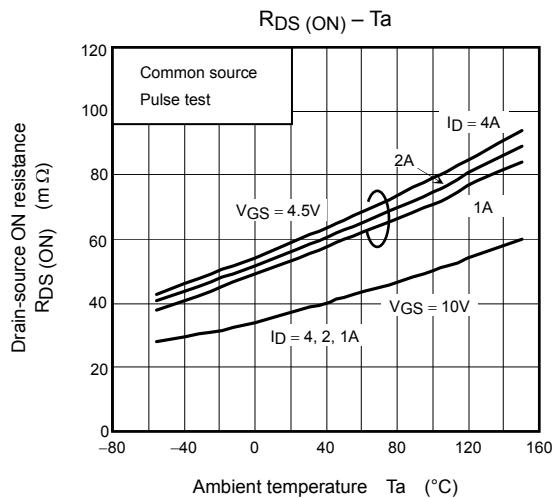
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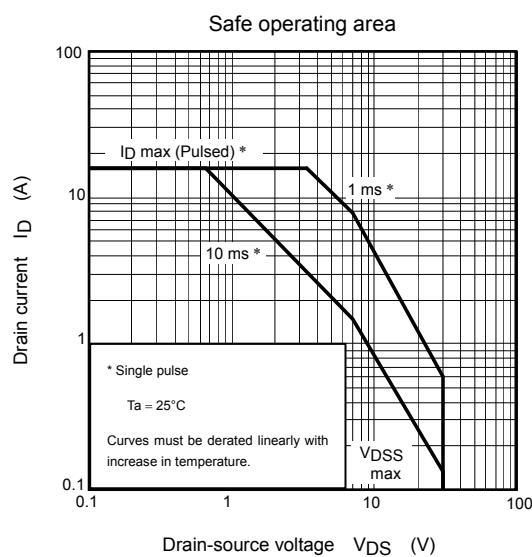
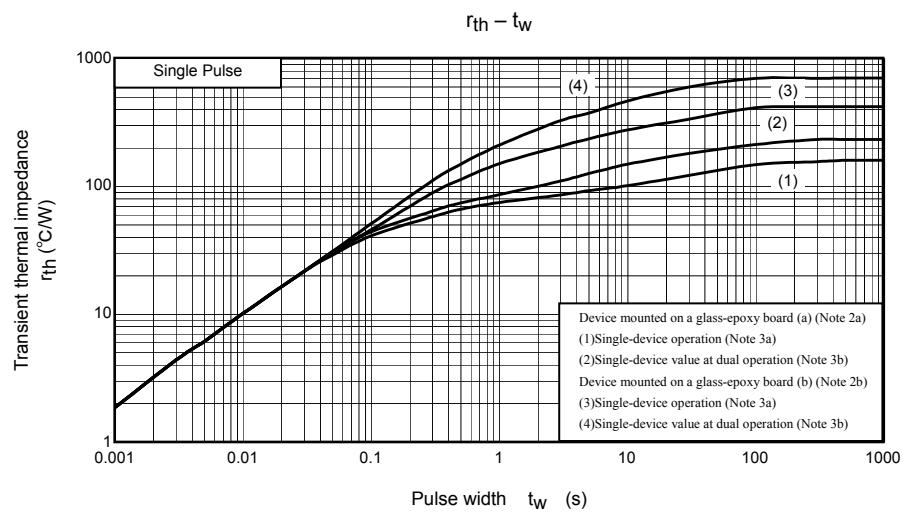
N-channel



N-channel



N-channel



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